

**■ Features :**

- Wide 2:1 DC input range
- In/out capacitance 1000pF
- Protections: Short circuit / Overload / Over voltage
- 1000VDC I/O isolation for D/D
- Cooling by free air convection
- Built-in remote ON-OFF control
- 100% full load burn-in test
- Fixed switching frequency at 225KHz
- Lost cost
- High reliability
- 1 year warranty

**SPECIFICATION**

MODEL	SDM30-12S3	SDM30-24S3	SDM30-48S3	SDM30-12S5	SDM30-24S5	SDM30-48S5	
OUTPUT	DC VOLTAGE	3.3V			5V		
	RATED CURRENT	5A			5A		
	CURRENT RANGE	0 ~ 5A			0 ~ 5A		
	RATED POWER	16.5W			25W		
	RIPPLE & NOISE (max.) Note.2	75mVp-p			75mVp-p		
	VOLTAGE TOLERANCE Note.3	±3.0%			±2.0% max.		
	LINE REGULATION	±1.0%			±1.0%		
	LOAD REGULATION	±1.0%			±1.0%		
TRIM OUTPUT	±13%(Typ.) output voltage			±10%(Typ.) output voltage			
INPUT	RATED DC INPUT	12S: 12VDC	24S: 24VDC	48S: 48VDC			
	VOLTAGE RANGE	12S: 9.2 ~ 18VDC	24S: 18 ~ 36VDC	48S: 36 ~ 72VDC			
	EFFICIENCY (Typ.)	77%	79%	80%	77%	79%	80%
	DC CURRENT	12S: 3.6A	24S: 2A	48S: 1A			
	IDLE CURRENT	12S: 35mA	24S/48S: 30mA				
PROTECTION	OVERLOAD	Above 105% rated output power Protection type : Over power limiting, recovers automatically after fault condition is removed					
	OVER VOLTAGE	3.8 ~ 4.95V			5.75 ~ 7.5V		
	SHORT CIRCUIT	Protection type : Constant current limiting, recovers automatically after fault condition is removed					
FUNCTION	ON/OFF CONTROL	Logic "1" or open: power on Logic "0" short to Vin-: power off					
ENVIRONMENT	WORKING TEMP.	-25 ~ +85°C (Refer to output load derating curve)					
	STORAGE TEMP., HUMIDITY	-25 ~ +85°C, 0 ~ 95% RH					
	TEMP. COEFFICIENT	±0.03%/°C (0~50°C)					
SAFETY & EMC (Note 6)	SAFETY STANDARDS	Design refer to LVD					
	ISOLATION VOLTAGE	I/P-O/P: 1KVDC					
	ISOLATION RESISTANCE	I/P-O/P: 100M Ohms/500VDC					
	EMI CONDUCTION & RADIATION	Compliance to EN55022 (CISPR22) Class B					
OTHERS	EMS IMMUNITY	Compliance to EN61000-2,3,4,6,8; ENV50204, EN55024, light industry level, criteria A					
	MTBF	322.4K hrs min. MIL-HDBK-217F (25°C)					
	DIMENSION	50.8*50.8*16mm (2"*2"*0.63") (L*W*H)					
	PACKING	0.1Kg; 150pcs/15.8Kg/0.97CUFT					
NOTE	1. All parameters NOT specially mentioned are measured at 12,24,48VDC input, rated load and 25°C of ambient temperature. 2. Ripple & noise are measured at 20MHz of bandwidth by using a 12" twisted pair-wire terminated with a 0.1uF & 47uF parallel capacitor. 3. Tolerance : includes set up tolerance, line regulation and load regulation. 4. Short circuit not more than 60 second. 5. DC source wires ≥ 5cm, an input external al capacitor 47 ~ 100uF is required. 6. The power supply is considered a component which will be installed into a final equipment. The final equipment must be re-confirmed that it still meets EMC directives.						

**■ Features :**

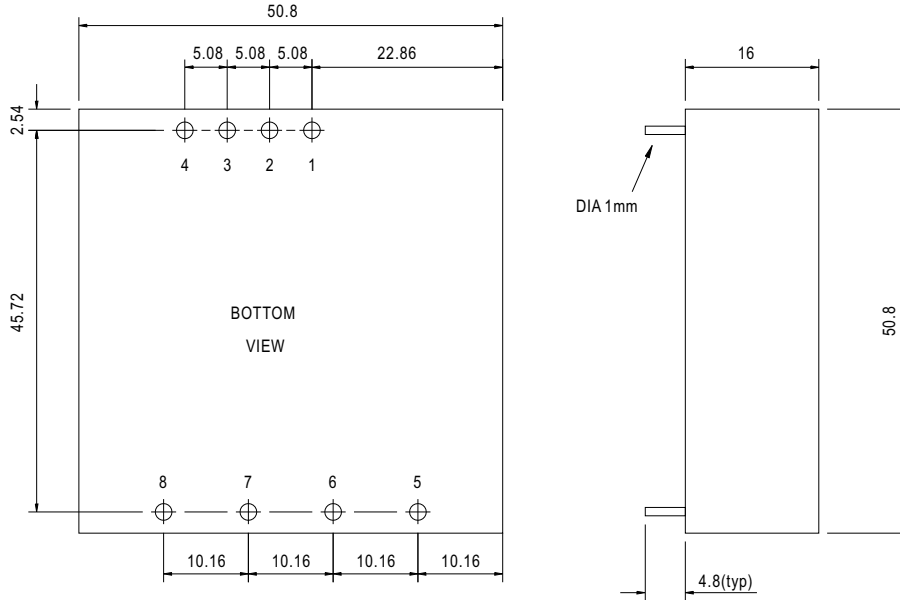
- Wide 2:1 DC input range
- In/out capacitance 1000pF
- Protections: Short circuit / Overload/ Over voltage
- 1000VDC I/O isolation for D/D
- Cooling by free air convection
- Built-in remote ON-OFF control
- 100% full load burn-in test
- Fixed switching frequency at 225KHz
- Lost cost
- High reliability
- 1 year warranty

**SPECIFICATION**

MODEL	SDM30-12S12	SDM30-24S12	SDM30-48S12	SDM30-12S15	SDM30-24S15	SDM30-48S15	
OUTPUT	DC VOLTAGE	12V			15V		
	RATED CURRENT	2.1A	2.5A		1.7A	2A	
	CURRENT RANGE	0 ~ 2.1A	0 ~ 2.5A		0 ~ 1.7A	0 ~ 2A	
	RATED POWER	25.2W	30W		25.5W	30W	
	RIPPLE & NOISE (max.) Note.2	100mVp-p			100mVp-p		
	VOLTAGE TOLERANCE Note.3	±2.0% max.			±2.0% max.		
	LINE REGULATION	±1.0%			±1.0%		
	LOAD REGULATION	±1.0%			±1.0%		
TRIM OUTPUT	±10%(Typ.) output voltage						
INPUT	RATED DC INPUT	12S: 12VDC	24S: 24VDC	48S: 48VDC			
	VOLTAGE RANGE	12S: 9.2 ~ 18VDC	24S: 18 ~ 36VDC	48S: 36 ~ 72VDC			
	EFFICIENCY (Typ.)	80%	82%	84%	80%	83%	85%
	DC CURRENT	12S: 3.6A	24S: 2A	48S: 1A			
	IDLE CURRENT	12S: 35mA	24S/48S: 30mA				
PROTECTION	OVERLOAD	Above 105% rated output power Protection type : Over power limiting, recovers automatically after fault condition is removed					
	OVER VOLTAGE	13.8 ~ 18V			17.25 ~ 22.5V		
	SHORT CIRCUIT	Protection type : Constant current limiting, recovers automatically after fault condition is removed					
FUNCTION	ON/OFF CONTROL	Logic "1" or open: power on Logic "0" short to Vin-: power off					
ENVIRONMENT	WORKING TEMP.	-25 ~ +85°C (Refer to output load derating curve)					
	STORAGE TEMP., HUMIDITY	-25 ~ +85°C, 0 ~ 95% RH					
	TEMP. COEFFICIENT	±0.03%/°C (0~50°C)					
SAFETY & EMC (Note 6)	SAFETY STANDARDS	Design refer to LVD					
	ISOLATION VOLTAGE	I/P-O/P: 1KVDC					
	ISOLATION RESISTANCE	I/P-O/P: 100M Ohms/500VDC					
	EMI CONDUCTION & RADIATION	Compliance to EN55022 (CISPR22) Class B					
OTHERS	EMS IMMUNITY	Compliance to EN61000-2,3,4,6,8; ENV50204, EN55024, light industry level, criteria A					
	MTBF	322.4K hrs min. MIL-HDBK-217F (25°C)					
	DIMENSION	50.8*50.8*16mm (2**2**0.63") (L*W*H)					
	PACKING	0.1Kg; 150pcs/15.8Kg/0.97CUFT					
NOTE	<ol style="list-style-type: none"> 1. All parameters NOT specially mentioned are measured at 12,24,48VDC input, rated load and 25°C of ambient temperature. 2. Ripple & noise are measured at 20MHz of bandwidth by using a 12" twisted pair-wire terminated with a 0.1uF & 47uF parallel capacitor. 3. Tolerance : includes set up tolerance, line regulation and load regulation. 4. Short circuit not more than 60 second. 5. DC source wires ≥5cm, an input external al capacitor 47 ~ 100uF is required. 6. The power supply is considered a component which will be installed into a final equipment. The final equipment must be re-confirmed that it still meets EMC directives. 						

■ Mechanical Specification

Case No. SDM-30 Unit:mm

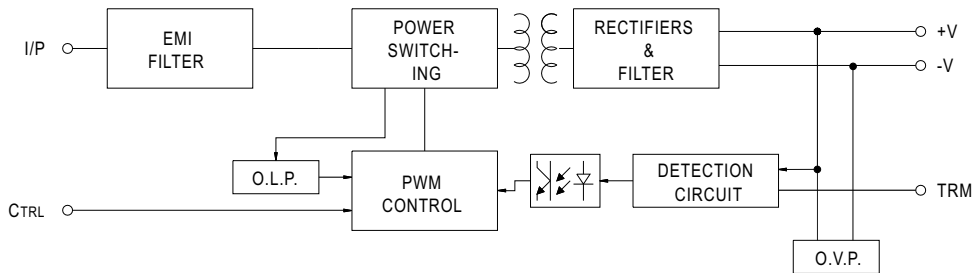


Pin No. Assignment

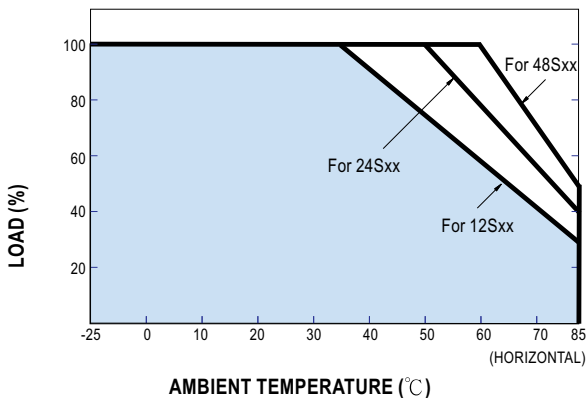
Pin No.	Assignment	Pin No.	Assignment
1	+Vin	6	+Vout
2	-Vin	7	-Vout
3,5	No pin	8	Trim
4	Control ON/OFF		

■ Block Diagram

fosc : 225KHz

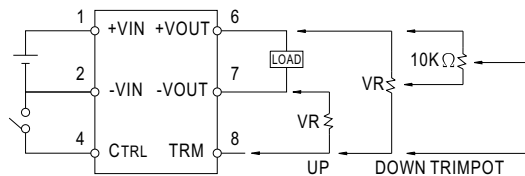


■ Derating Curve



■ External Output Trimming

OUTPUT MAY OPTIONALLY BE EXTERNALLY TRIMMED(±10%)
A FIXED RESISTOR OR AN EXTERNAL TRIMPOT AS SHOWN



■ ON/OFF Control Pin

CONTROL INPUT.....PIN4
CONTROL COMMON.....PIN2
LOGIC COMPATIBILITY.....CMOS OR OPEN COLLECTOR TTL
CONTROL VOLTAGE
ON.....+5.5VDC min OR OPEN CIRCUIT
OFF.....+2.5VDC max. OR SHORT TO PIN2

MODEL : SDM30-24S12

OUTPUT FUNCTION TEST

NO	TEST ITEM	SPECICATION	TEST CONDITION	RESULT	VERDICT
1	RIPPLE & NOISE	V1: 100 mVp-p (Max)	I/P: 24 VDC O/P:FULL LOAD Ta:25°C	V1: 11 mVp-p (Max)	P
2	OUTPUT VOLTAGE TOLERANCE	V1: +2%~-2% (Max)	I/P: 18 VDC / 36 VDC O/P:FULL/ MIN LOAD Ta:25°C	V1: 0.06%~-0.06%	P
3	LINE REGULATION	V1: +1%~-1% (Max)	I/P: 18 VDC ~ 36 VDC O/P:FULL LOAD Ta:25°C	V1: 0.0%~-0.06%	P
4	LOAD REGULATION	V1: +1%~-1% (Max)	I/P: 24 VDC O/P:FULL ~MIN LOAD Ta:25°C	V1: 0.06%~-0.06%	P
5	OVER/UNDERSHOOT TEST	< ±5%	I/P: 24 VDC O/P:FULL LOAD Ta:25°C	TEST: < 5%	P
6	DYNAMIC LOAD	V1: 1200 mVp-p	I/P: 24 VDC O/P:FULL /Min LOAD 90%DUTY/1KHZ Ta:25°C	422 mVp-p	P
7	TRIM OUTPUT	V1: 10% output voltage (Typ)	I/P: 24 VDC O/P:FULL LOAD Ta:25°C	V1: 13.075V	P

INPUT FUNCTION TEST

NO	TEST ITEM	SPECICATION	TEST CONDITION	RESULT	VERDICT
1	INPUT VOLTAGE RANGE	18VDC~36 VDC	I/P:TESTING O/P:FULL LOAD Ta:25°C	15 V~36 V	P
			I/P: LOW-LINE-3V= 15 VDC HIGH-LINE+3%= 37 VDC O/P:FULL/MIN LOAD ON: 30 Sec . OFF: 30 Sec 10MIN (AC POWER ON/OFF NO DAMAGE)	TEST: OK	
2	EFFICIENCY	82% (TYP)	I/P: 24 VDC O/P:FULL LOAD Ta:25°C	82.14 %	P
3	INPUT CURRENT	24 V/ 2 A (Max)	I/P: 24 VDC O/P:FULL LOAD Ta:25°C	I=1.47 A	P
4	IDEL CURRENT	30mA / 24 VDC	I/P: 24 VDC O/P:Min LOAD Ta:25°C	I = 18.96 mA	P

PROTECTION FUNCTION TEST

NO	TEST ITEM	SPECICATION	TEST CONDITION	RESULT	VERDICT
1	OVER LOAD PROTECTION	> 105 %	I/P: 24 VDC I/P: 18 VAC O/P: TESTING Ta: 25°C	110%/ 24 VDC 114%/ 18 VDC Over Power Limiting	P
2	OVER VOLTAGE PROTECTION	CH1: 13.8V~ 18.0 V	I/P: 24 VDC I/P: 18 VAC O/P: MIN LOAD Ta: 25°C	16.6V/ 24 VDC 16.6V/ 18 VDC Shunt down Re- power ON	P
3	SHORT PROTECTION	SHORT EVERY OUTPUT 1 HOUR NO DAMAGE	I/P: 36 VDC O/P: 100% LOAD Ta: 25°C	NO DAMAGE Constant Current Limiting	P

CONTROL FUNCTION TEST

NO	TEST ITEM	SPECICATION	TEST CONDITION	RESULT	VERDICT
1	ON/OFF CONTROL	Logic * 1 * or Open POWER ON Logic * 0 * or Short POWER OFF	I/P: 24VDC/O/P: FULL LOAD Ta: 25°C	Logic * 1 * or Open POWER ON Logic * 0 * or Short POWER OFF	P

ENVIRONMENT TEST

NO	TEST ITEM	SPECIFICATION	TEST CONDITION	RESULT	VERDICT																																																																																
1	TEMPERATURE RISE TEST	MODEL : SDM30-24S5 1. ROOM AMBIENT BURN-IN : 87 HRS I/P: 24 VDC O/P: 100% LOAD Ta= 27.2 °C 2. HIGH AMBIENT BURN-IN : 15 HRS I/P: 24 VDC O/P: 100% LOAD Ta= 48.6 °C			P																																																																																
		<table border="1"> <thead> <tr> <th>NO</th> <th>Position</th> <th>P/N</th> <th>ROOM AMBIENT Ta= 27.2 °C</th> <th>HIGH AMBIENT Ta= 48.6 °C</th> </tr> </thead> <tbody> <tr><td>1</td><td>U1</td><td>MIC38C43BM</td><td>79.0°C</td><td>95.4°C</td></tr> <tr><td>2</td><td>Q2</td><td>BJT BCX56 1A/80V</td><td>80.6°C</td><td>96.8°C</td></tr> <tr><td>3</td><td>Q3</td><td>BJT 2SA1797 -2A/-50V</td><td>80.5°C</td><td>97.2°C</td></tr> <tr><td>4</td><td>L3</td><td>TR 273</td><td>81.2°C</td><td>97.3°C</td></tr> <tr><td>5</td><td>L2</td><td>DRS001A</td><td>78.0°C</td><td>94.3°C</td></tr> <tr><td>6</td><td>D1</td><td>SMD EC11FS2-TE12L</td><td>80.3°C</td><td>96.5°C</td></tr> <tr><td>7</td><td>C52</td><td>C/E 470u/10V</td><td>79.4°C</td><td>95.5°C</td></tr> <tr><td>8</td><td>C54</td><td>C/E 33u/10V</td><td>83.3°C</td><td>99.6°C</td></tr> <tr><td>9</td><td>D50</td><td>SBD DF30SC4M 30A/40V</td><td>84.4°C</td><td>100.4°C</td></tr> <tr><td>10</td><td>T1core</td><td>CT TS013</td><td>81.6°C</td><td>97.7°C</td></tr> <tr><td>11</td><td>T1coil</td><td>CT TS013</td><td>83.3°C</td><td>99.8°C</td></tr> <tr><td>12</td><td>C5</td><td>105/50V</td><td>79.0°C</td><td>95.2°C</td></tr> <tr><td>13</td><td>L1</td><td>DRS003B</td><td>79.9°C</td><td>96.3°C</td></tr> <tr><td>14</td><td>T2</td><td>CT TS013</td><td>81.3°C</td><td>97.6°C</td></tr> <tr><td>15</td><td>Q1</td><td>FET CEB</td><td>82.6°C</td><td>99.1°C</td></tr> </tbody> </table>	NO	Position		P/N	ROOM AMBIENT Ta= 27.2 °C	HIGH AMBIENT Ta= 48.6 °C	1	U1	MIC38C43BM	79.0°C	95.4°C	2	Q2	BJT BCX56 1A/80V	80.6°C	96.8°C	3	Q3	BJT 2SA1797 -2A/-50V	80.5°C	97.2°C	4	L3	TR 273	81.2°C	97.3°C	5	L2	DRS001A	78.0°C	94.3°C	6	D1	SMD EC11FS2-TE12L	80.3°C	96.5°C	7	C52	C/E 470u/10V	79.4°C	95.5°C	8	C54	C/E 33u/10V	83.3°C	99.6°C	9	D50	SBD DF30SC4M 30A/40V	84.4°C	100.4°C	10	T1core	CT TS013	81.6°C	97.7°C	11	T1coil	CT TS013	83.3°C	99.8°C	12	C5	105/50V	79.0°C	95.2°C	13	L1	DRS003B	79.9°C	96.3°C	14	T2	CT TS013	81.3°C	97.6°C	15	Q1	FET CEB	82.6°C	99.1°C		
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15	Q1	FET CEB	82.6°C	99.1°C																																																																																	
2	OVER LOAD BURN-IN TEST	NO DAMAGE 1 HOUR (MIN)	I/P: 24 VDC O/P: 120 % LOAD Ta:25°C	TEST : OK	P																																																																																
3	LOW TEMPERATURE TURN ON TEST	TURN ON AFTER 2 HOUR	I/P: 24 VDC O/P: 100 % LOAD Ta= -8.8 °C	TEST : OK	P																																																																																
4	HIGH HUMIDITY HIGH TEMPERATURE HIGH VOLTAGE TURN ON TEST	AFTER 12 HOURS IN CHAMBER ON CONTROL 25 °C NO DAMAGE	I/P: 36 VDC O/P:FULL LOAD Ta= 25 °C HUMIDITY= 95 %R.H	TEST : OK	P																																																																																
5	TEMPERATURE COEFFICIENT	± 0.03 % (0~50°C)	I/P: 24 VDC O/P:FULL LOAD	± 0.01 % (0~50°C)	P																																																																																



SAFETY TEST

NO	TEST ITEM	SPECICATION	TEST CONDITION	RESULT	VERDICT
1	WITHSTAND VOLTAGE	I/P-O/P: 1 KVDC/min	I/P-O/P: 1.2 KVDC/min Ta:25°C	I/P-O/P: 0.002 mA NO DAMAGE	P
2	ISOLATION RESISTANCE	I/P-O/P:500VDC>100MΩ	I/P-O/P: 500 VDC Ta:25°C	I/P-O/P: 1.2G Ω NO DAMAGE	P

M.T.B.F & LIFE CYCLE CALCULATION

NO	TEST ITEM	SPECICATION	TEST CONDITION	RESULT	VERDICT
1	MTBF	MIL-HDBK-217F NOTICES2 PARTS COUNT TOTAL FAILURE RATE: 322.4K HRS			P

DATE	SAMPLE	TEST RESULT	TESTER	APPROVAL
2000/09/09	RD SAMPLE	PASS	VINCENT TSENG	MAX LIN
2002/12/7	PRODUCT SAMPLE A211A14	PASS	VINCENT TSENG	MAX LIN

2003/12/12 A50-F023